

10A01 - 10A07

AXIAL LEADED SILICON RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V CURRENT: 10.0 A

Features

Diffused Junction

 High Current Capability and Low Forward Voltage Drop

Low Reverse Leakage Current

 Plastic Material - UL Flammability Classification 94V-0

Mechanical Data

Case: R-6, Molded Plastic

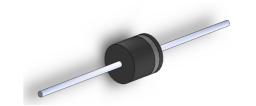
Terminals: Plated Leads Solderable per

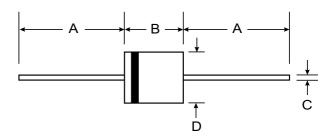
MIL-STD-202, Method 208Polarity: Cathode Band

Marking: Type Number

Weight: 2.1 grams (approx)







R-6							
Dim	Min	Max					
Α	25.4	_					
В	8.6	9.1					
С	1.2	1.3					
All Dimensions in mm							

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

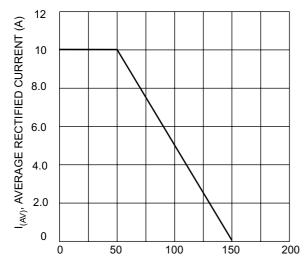
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	10A01	10A02	10A03	10A04	10A05	10A06	10A07	Unit
Peak Repetitive Reverse Voltage	V_{RRM}								
Working Peak Reverse Voltage DC Blocking Voltage	V_{RWM} V_{R}	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @ T _A = 50°C	, lo	10					Α		
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}				600				Α
Forward Voltage @ I _F = 10.	4 V _{FM}	1.0						V	
10Peak Reverse Current @T _A = 25° at Rated DC Blocking Voltage @ T _A = 100°	C I _{RM}	10 100						μΑ	
Typical Junction Capacitance (Note 2)	Cj		1:	50			80		pF
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	10			K/W				
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150					°C		

Notes:

- 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.
- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.





T_A, AMBIENT TEMPERATURE (°C) Fig. 1 Forward Current Derating Curve

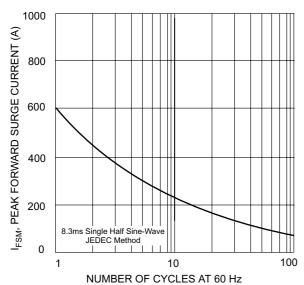


Fig. 3 Maximum Non-Repetitive Peak Forward Surge Current

